

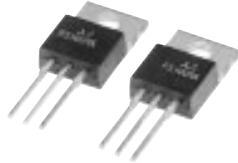
PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

MITSUBISHI Nch POWER MOSFET

FS10UMA-5A

HIGH-SPEED SWITCHING USE

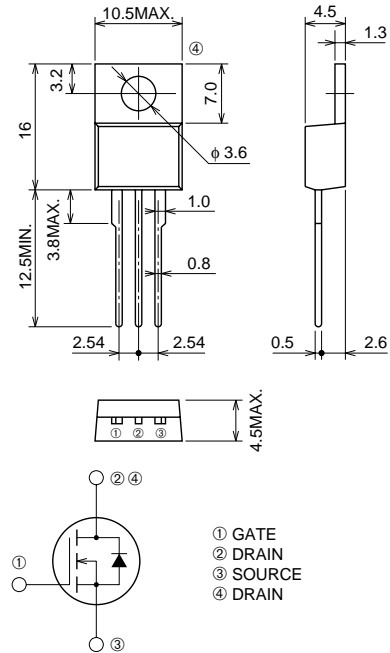
FS10UMA-5A



- 10V DRIVE
- V_{DSS} 250V
- r_{DS (ON)} (MAX) 0.52Ω
- I_D 10A

OUTLINE DRAWING

Dimensions in mm



TO-220

APPLICATION

Cs Switch for CRT Display monitor

MAXIMUM RATINGS (T_c = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{DSS}	Drain-source voltage	V _{GS} = 0V	250	V
V _{GSS}	Gate-source voltage	V _{DS} = 0V	±20	V
I _D	Drain current		10	A
I _{DM}	Drain current (Pulsed)		30	A
I _{DA}	Avalanche current (Pulsed)	L = 200μH	10	A
P _D	Maximum power dissipation		65	W
T _{ch}	Channel temperature		-55 ~ +150	°C
T _{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	2.0	g

Jan. 2000

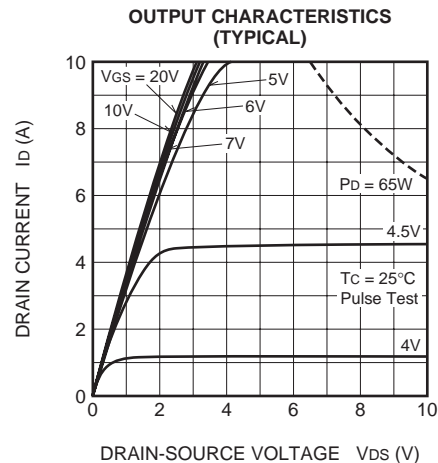
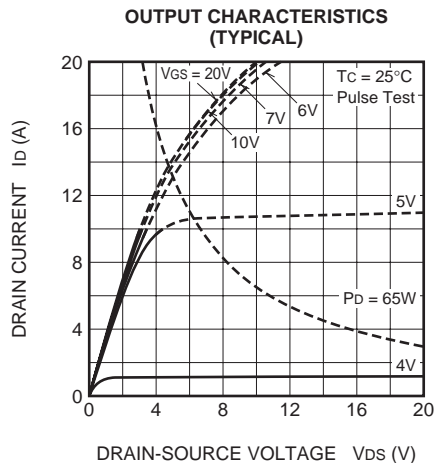
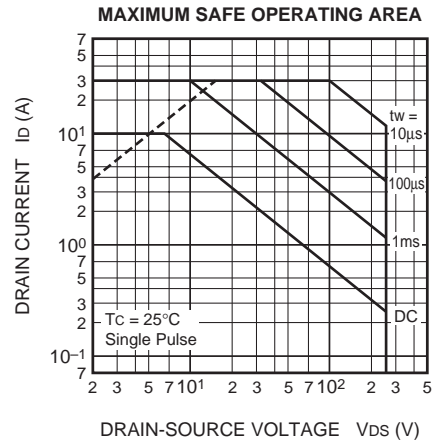
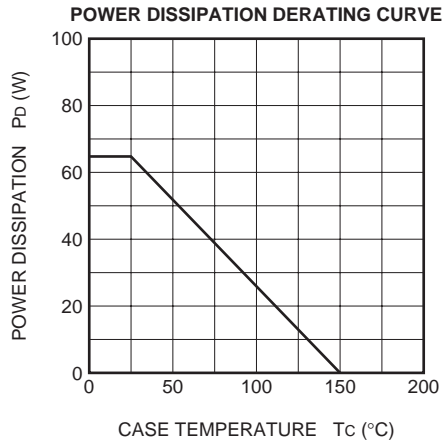


PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

ELECTRICAL CHARACTERISTICS (T_{ch} = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	I _D = 1mA, V _{GS} = 0V	250	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±20V, V _{DS} = 0V	—	—	±0.1	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 250V, V _{GS} = 0V	—	—	1	mA
V _{GS} (th)	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	2.0	3.0	4.0	V
r _{DS} (ON)	Drain-source on-state resistance	I _D = 5A, V _{GS} = 10V	—	0.40	0.52	Ω
V _{DS} (ON)	Drain-source on-state voltage	I _D = 5A, V _{GS} = 10V	—	2.00	2.60	V
y _{fs}	Forward transfer admittance	I _D = 5A, V _{DS} = 10V	—	9.0	—	S
C _{iss}	Input capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	—	950	—	pF
C _{oss}	Output capacitance		—	90	—	pF
C _{rss}	Reverse transfer capacitance		—	25	—	pF
t _d (on)	Turn-on delay time	V _{DD} = 150V, I _D = 5A, V _{GS} = 10V, R _{GEN} = R _{GS} = 50Ω	—	20	—	ns
t _r	Rise time		—	25	—	ns
t _d (off)	Turn-off delay time		—	150	—	ns
t _f	Fall time		—	40	—	ns
V _{SD}	Source-drain voltage	I _S = 5A, V _{GS} = 0V	—	1.5	2.0	V
R _{th} (ch-c)	Thermal resistance	Channel to case	—	—	1.92	°C/W

PERFORMANCE CURVES

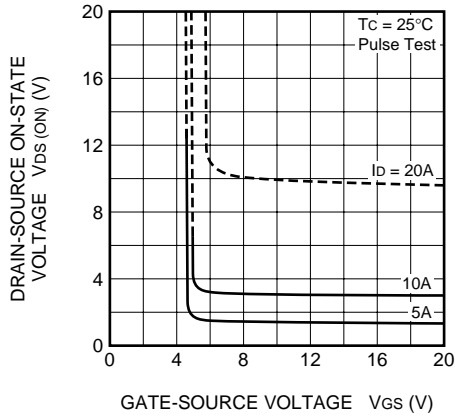


FS10UMA-5A

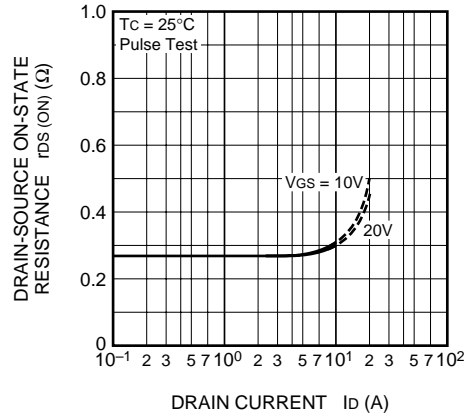
HIGH-SPEED SWITCHING USE

PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

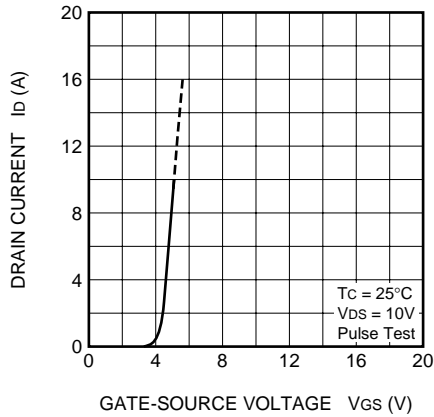
ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)



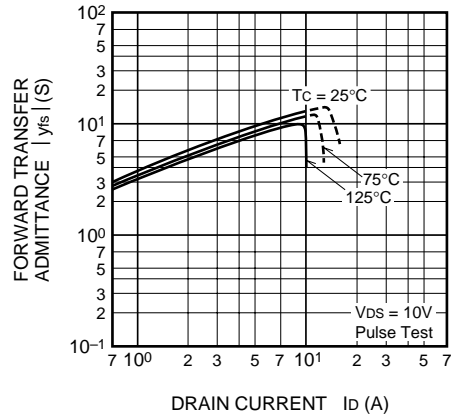
ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)



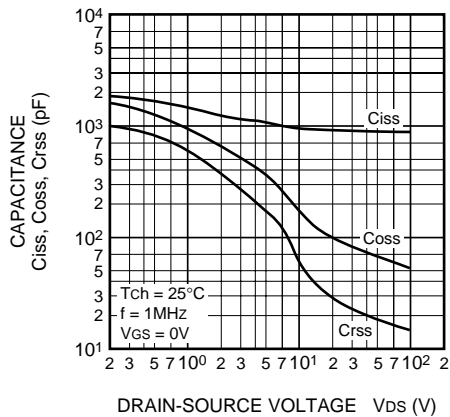
TRANSFER CHARACTERISTICS (TYPICAL)



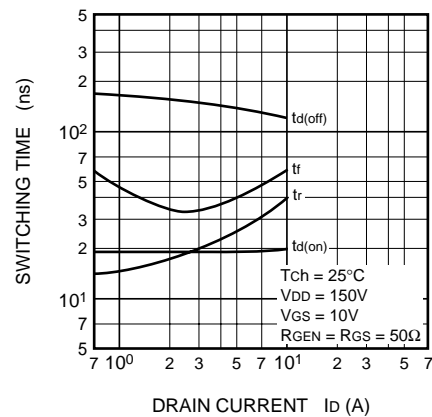
FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)



CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)



SWITCHING CHARACTERISTICS (TYPICAL)



PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

